# NPN Darlington Power Transistor

This high voltage power Darlington has been specifically designed for inductive applications such as Electronic Ignition, Switching Regulators and Motor Control.

### Features

- Exceptional Safe Operating Area
- High V<sub>CE</sub>; High Current Gain
- These are Pb–Free Devices

### Benefits

- Reliable Performance at Higher Powers
- Designed for Inductive Loads
- Very Low Current Requirements

### Applications

- Internal Combustion Engine Ignition Control
- Switching Regulators
- Motor Controls
- Light Ballast
- Photo Flash

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Sustaining Voltage	V <sub>CEO</sub>	350	Vdc
Collector-Base Breakdown Voltage	V <sub>CBO</sub>	700	Vdc
Collector-Emitter Breakdown Voltage	V <sub>CES</sub>	700	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	Vdc
Collector Current Continuous Peak	I <sub>C</sub> I <sub>CM</sub>	4.0 8.0	Adc
Base Current	Ι <sub>Β</sub>	0.5	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	45 0.36	W W/∘C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance Junction-to-Case	$R_{ heta JC}$	2.78	°C/W
Junction-to-Ambient	$R_{ heta JA}$	71.4	



## **ON Semiconductor®**

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# DARLINGTON POWER TRANSISTORS 4 AMPERES 350 VOLTS 45 WATTS

MARKING DIAGRAM



Y = Year WW = Work Week NJD35N04 = Device Code G = Pb-Free Device

### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NJD35N04G	DPAK (Pb–Free)	75 Units / Rail
NJD35N04T4G	DPAK (Pb-Free)	2500/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Semiconductor Components Industries, LLC, 2006 April, 2006 – Rev. 1 Publication Order Number: NJD35N04/D

## **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = $25^{\circ}$ C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Мах	Unit
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage $(I_C = 10 \text{ mA}, L = 10 \text{ mH})$	V <sub>CEO(sus)</sub>	350	-	-	Vdc
Collector Cutoff Current (V <sub>CE</sub> = 500 V) (I <sub>B</sub> = 0) (V <sub>CE</sub> = 500 V, T <sub>C</sub> = 125°C)	ICES		-	50 250	μAdc
Collector Cutoff Current (V <sub>CE</sub> = 350 V) (I <sub>B</sub> = 0) (V <sub>CE</sub> = 300 V, T <sub>C</sub> = 125°C)	ICEO			50 250	μAdc
Emitter Cutoff Current (V <sub>BE</sub> = 5.0 Vdc)	I <sub>EBO</sub>	-	-	5.0	μAdc
ON CHARACTERISTICS					
Collector–Emitter Saturation Voltage ( $I_C = 2.0 \text{ A}, I_B = 20 \text{ mA}$ ) ( $I_C = 2.0 \text{ A}, I_B = 20 \text{ mA } 125^{\circ}\text{C}$ )	V <sub>CE(sat)</sub>	-	-	1.5	Vdc
Base-Emitter Saturation Voltage ( $I_C = 2.0 \text{ A}, I_B = 20 \text{ mA}$ ) ( $I_C = 2.0 \text{ A}, I_B = 20 \text{ mA } 125^{\circ}\text{C}$ )	V <sub>BE(sat)</sub>	-	-	2.0	Vdc
Base-Emitter On Voltage $(I_{C} = 2.0 \text{ A}, V_{CE} = 2.0 \text{ V})$ $(I_{C} = 2.0 \text{ A}, V_{CE} = 2.0 \text{ V} 125^{\circ}\text{C})$	V <sub>BE(on)</sub>	-	-	2.0	Vdc
DC Current Gain $(I_C = 2.0 \text{ A}, V_{CE} = 2.0 \text{ V})$ $(I_C = 4.0 \text{ A}, V_{CE} = 2.0 \text{ Vdc})$	h <sub>FE</sub>	2000 300		-	-
DYNAMIC CHARACTERISTICS					
Current–Gain – Bandwidth Product ( $I_C = 2.0 \text{ A}, V_{CE} = 10 \text{ V}, f = 1.0 \text{ MHz}$ )	f <sub>T</sub>	90	_	_	MHz
Output Capacitance $(V_{CB} = 10 \text{ V}, I_E = 0, f = 0.1 \text{ MHz})$	C <sub>ob</sub>	-	60	-	pF
SWITCHING CHARACTERISTICS					
$V_{CC} = 12 \text{ V}, V_{clamp} = 250 \text{ V}, L = 4 \text{ mH}$ $I_C = 2 \text{ A}, I_{B1} = 20 \text{ mA}, I_{B2} = -20 \text{ mA}$	t <sub>s</sub> t <sub>f</sub>		18 0.8		μSec

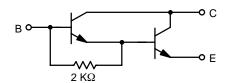
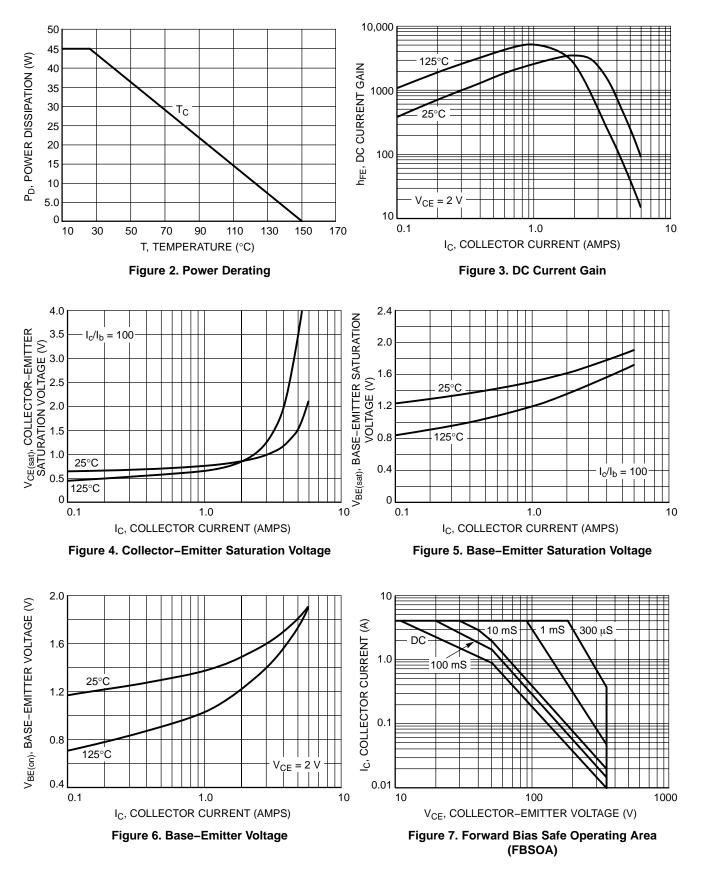


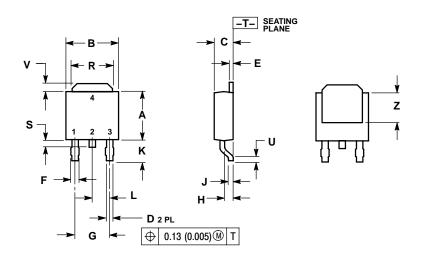
Figure 1.	Darlington	Circuit	Schematic
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### **TYPICAL CHARACTERISTICS**



#### PACKAGE DIMENSIONS

DPAK CASE 369C-01 ISSUE O



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH.

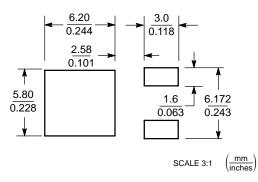
	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.235	0.245	5.97	6.22	
в	0.250	0.265	6.35	6.73	
С	0.086	0.094	2.19	2.38	
D	0.027	0.035	0.69	0.88	
Е	0.018	0.023	0.46	0.58	
F	0.037	0.045	0.94	1.14	
G	0.180 BSC		4.58 BSC		
н	0.034	0.040	0.87	1.01	
J	0.018	0.023	0.46	0.58	
Κ	0.102	0.114	2.60	2.89	
L	0.090 BSC		2.29 BSC		
R	0.180	0.215	4.57	5.45	
S	0.025	0.040	0.63	1.01	
U	0.020		0.51		
۷	0.035	0.050	0.89	1.27	
Ζ	0.155		3.93		

STYLE 1: PIN 1. BASE

2. COLLECTOR 3. EMITTER

4. COLLECTOR

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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